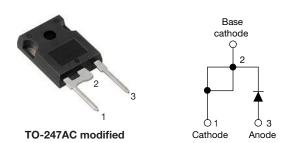


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Vishay Semiconductors

High Voltage Input Rectifier Diode, 60 A



PRODUCT SUMMARY						
Package	TO-247AC modified (2 pins)					
I _{F(AV)}	60 A					
V_{R}	800 V to 1200 V					
V _F at I _F	1.09 V					
I _{FSM}	1000 A					
T _J max.	150 °C					
Diode variation	Single die					

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912







APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Sinusoidal waveform	60	Α						
V _{RRM}		800/1200	V						
I _{FSM}		1000	Α						
V _F	60 A, T _J = 25 °C	1.09	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-60EPS08PbF, VS-60EPS08-M3	800	900	1						
VS-60EPS12PbF, VS-60EPS12-M3	1200	1300	1						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	$T_C = 118$ °C, 180 ° conduction half sine wave	60					
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	840	Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	1000					
Maximum I2t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	3530					
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	4220	— A ² s				
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	42 200	A²√s				



VS-60EPS...PbF Series, VS-60EPS..-M3 Series

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS		
Maximum famuard valtage drap		30 A, T _J = 25 °C		1.0	V		
Maximum forward voltage drop	V_{FM}	60 A, T _J = 25 °C		1.09	V		
Forward slope resistance	r _t	T _{.1} = 150 °C		3.96	mΩ		
Threshold voltage	V _{F(TO)}	1 _J = 150 C		0.74	V		
Maximum various lackage accurant		T _J = 25 °C	V Dated V	0.1	A		
Maximum reverse leakage current	I _{RM}	T ₁ = 150 °C	V_R = Rated V_{RRM}	1.0	mA		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, unction to case		R _{thJC}	DC operation	0.35				
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.2				
Approximate weight				6	g			
Approximate weight				0.21	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque –	maximum			12 (10) (lbf · i				
Marking device			Coop style TO 247AC modified / IEDEC)	60EPS08				
			Case style TO-247AC modified (JEDEC)	60EPS12				

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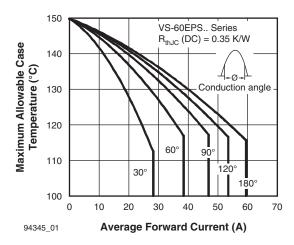


Fig. 1 - Current Rating Characteristics

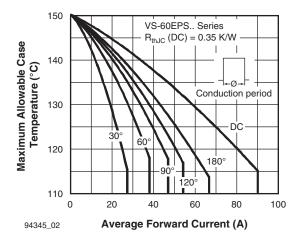


Fig. 2 - Current Rating Characteristics

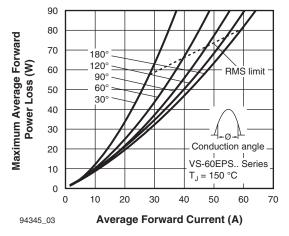


Fig. 3 - Forward Power Loss Characteristics

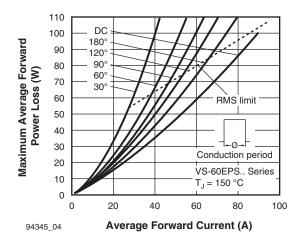


Fig. 4 - Forward Power Loss Characteristics

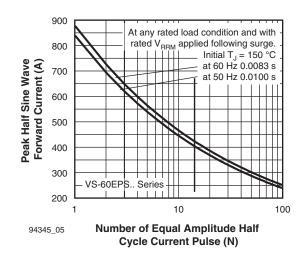


Fig. 5 - Maximum Non-Repetitive Surge Current

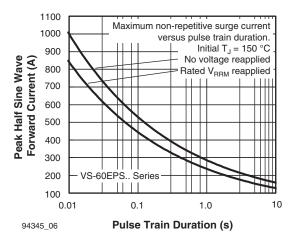


Fig. 6 - Maximum Non-Repetitive Surge Current

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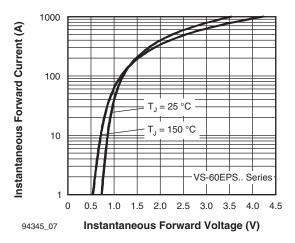


Fig. 7 - Forward Voltage Drop Characteristics

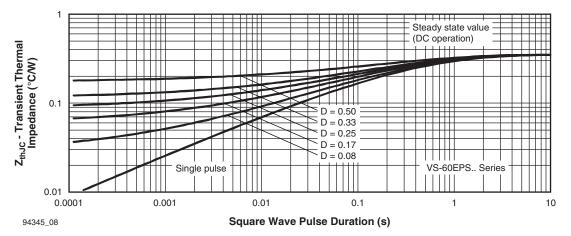


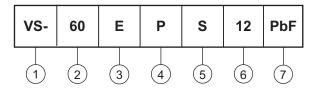
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

VS-60EPS...PbF Series, VS-60EPS...-M3 Series

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ORDERING INFORMATION TABLE





1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

3 - Circuit configuration:

E = single diode

- Package:

P = TO-247AC modified

5 - Type of silicon:

S = standard recovery rectifier

7 - Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

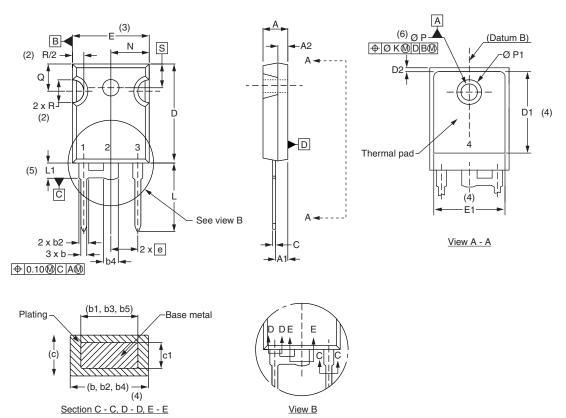
ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-60EPS08PbF	25	500	Antistatic plastic tubes						
VS-60EPS08-M3	25	500	Antistatic plastic tubes						
VS-60EPS12PbF	25	500	Antistatic plastic tubes						
VS-60EPS12-M3	25	500	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95541</u>							
Part marking information	TO-247AC modified PbF	www.vishay.com/doc?95255					
	TO-247AC modified -M3	www.vishay.com/doc?95442					
SPICE model		www.vishay.com/doc?95625					

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TO-247 - 50 mils L/F modified

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		INCHES			SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	OTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

- (1) Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



Legal Disclaimer Notice

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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